

SGM4782 0.5Ω, High Speed, Low Voltage Analog Switch/Multiplexer

GENERAL DESCRIPTION

The SGM4782 is high-speed, low-voltage, low on-resistance, CMOS analog multiplexer/switch that configured as two 4-channel multiplexers. It operates from a single +1.8V to +4.2V power supply. Targeted applications include battery powered equipment that benefit from low R_{ON} (0.5 Ω) and fast switching speeds (t_{ON} = 20ns, t_{OFF} = 20ns).

The SGM4782 can handle rail-to-rail analog signals and is available in Green TQFN-3×3-16L and TSSOP-16 packages.

FEATURES

Voltage Operation: 1.8V to 4.2V

• Low On-Resistance: 0.5Ω (TYP) at 4.2V

• Low On-Resistance Flatness

• -3dB Bandwidth: 30MHz

• Fast Switching Times (+4.2V)

t_{ON} 20ns t_{OFF} 20ns

Low Crosstalk: -108dB at 1MHz

• Typical Power Consumption (< 0.01μW)

• TTL/CMOS Compatible

• Rail-to-Rail Input and Output Operation

Break-Before-Make Switching

• -40°C to +85°C Operating Temperature Range

 Available in Green TQFN-3×3-16L and TSSOP-16 Packages

APPLICATIONS

Communication Systems
Cell Phones
Portable Instrumentation
Audio Signal Routing
Audio and Video Switching
Computer Peripherals
Low-Voltage Data-Acquisition Systems



PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
	TQFN-3×3-16L	-40°C to +85°C	SGM4782YTQ16/TR	4782TQ XXXXX	Tape and Reel, 3000
SGM4782	TSSOP-16	-40°C to +85°C	SGM4782YTS/TR	SGM4782 YTS XXXXX	Tape and Reel, 3000

NOTE: XXXXX = Date Code and Vendor Code.

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

V+ to GND	0V to 4.6V
Analog, Digital Voltage Range	0.3V to (V_+) + 0.3V
Continuous Current X_, Y_, X or Y	±250mA
Peak Current X_, Y_, X or Y	±400mA
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	4000V
MM	400V

NOTE: 1. Voltages exceeding V_{CC} or V_{EE} on any signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range-40°C to +85°C

OVERSTRESS CAUTION

Stresses beyond those listed may cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational section of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

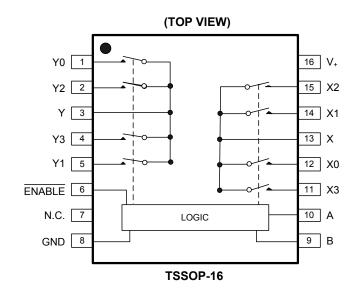
DISCLAIMER

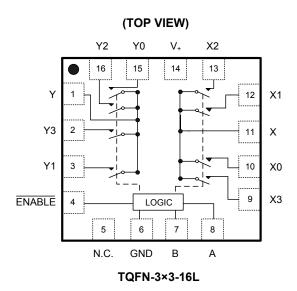
SG Micro Corp reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PIN CONFIGURATIONS





PIN DESCRIPTION

PIN		NAME	FUNCTION
TSSOP-16	TQFN-3×3-16L	NAME	FUNCTION
1, 5, 2, 4	15, 3, 16, 2	Y0-Y3	Analog Switch Y Inputs Y0-Y3.
3	1	Y	Analog Switch Y Output.
6	4	ENABLE	Digital Enable Input. Normally connect to GND. Drive to logic high to set all switches off.
7	5	N.C.	Not Internally Connected.
8	6	GND	Ground.
9	7	В	Digital Address B Input.
10	8	А	Digital Address A Input.
12, 14, 15, 11	10, 12, 13, 9	X0-X3	Analog Switch X Inputs X0-X3.
13	11	X	Analog Switch X Output.
16	14	V+	Positive Analog and Digital Supply Voltage Input.
_	Exposed Pad	GND	Exposed pad should be soldered to PCB board and connected to GND.

FUNCTION TABLE

CO	NTROL INPUT				
Enable	Sel	ect	ON SWITCHES		
Ellable	В	Α			
L	L	L	X-X0 Y-Y0		
L	L	Н	X-X1 Y-Y1		
L	Н	L	X-X2 Y-Y2		
L	Н	Н	X-X3 Y-Y3		
Н	V	$\sqrt{}$	All Switches Open		

NOTE: $\sqrt{\ }$ = Don't Care.

ELECTRICAL CHARACTERISTICS

 $(V_+ = +4.2V, \text{ GND} = 0V, V_{IH} = +1.6V, V_{IL} = +0.6V, \text{ Full} = -40^{\circ}\text{C}$ to +85°C. Typical values are at $V_+ = +4.2V, T_A = +25^{\circ}\text{C}$, unless otherwise noted.)

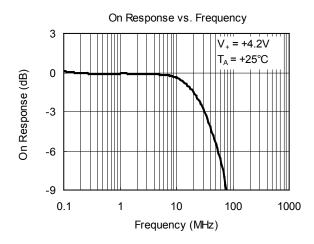
PARAMETER	SYMBOL	CONDITIONS		TEMP	MIN	TYP	MAX	UNITS
ANALOG SWITCH								
Analog Signal Range	$V_{X}, V_{Y}, V_{X_+}, V_{Y}$			Full	0		V ₊	V
On Bosistanos		V ₊ = 4.2V, I _X , I _Y = -100mA, V _X ,	V _Y = 1V,	+25°C		0.5	0.85	
On-Resistance	R _{on}	Test Circuit 1		Full			0.95	Ω
On-Resistance Match Between	ΔR_{ON}	$V_{+} = 4.2V$, $I_{X_{-}}$, $I_{Y_{-}} = -100$ mA, V_{X} , $V_{Y} = 1V$, Test Circuit 1		+25°C		0.05	0.2	Ω
Channels	ΔNON			Full			0.24	12
On-Resistance Flatness	R _{FLAT(ON)}	V ₊ = 4.2V, I _{X_} , I _{Y_} = -100mA,				0.1	0.2	Ω
On resistance riamess	TTELAT(ON)	V_X , V_Y = 1V, 2.5V, Test Circuit 1		Full			0.24	
Source OFF Leakage Current	I _{X_(OFF)} , I _{Y_(OFF)}	$V_{+} = 4.2V, V_{X_{-}}, V_{Y_{-}} = 3.3V, 0.3V, V_{X}, V_{Y} = 0.3V, 3.3V$	ī	Full			1	μΑ
Channel ON Leakage Current	$I_{X_{-}(ON)}, I_{Y_{-}(ON)}, I_{X(ON)}, I_{Y(ON)}$	$V_{+} = 4.2V$, V_{X} , $V_{Y} = 0.3V$, $3.3V$, $V_{X_{-}}$, $V_{Y_{-}} = 0.3V$, $3.3V$ or floating		Full			1	μΑ
DIGITAL INPUTS								
Input High Voltage	V _{INH}			Full	1.6			V
Input Low Voltage	V _{INL}			Full			0.5	V
Input Leakage Current	I _{IN} _	V _A , V _B = V _{ENABLE} = 0V or 4.2V		Full			1	μΑ
DYNAMIC CHARACTERISTICS								
Turn-On Time	t _{ON}	V_{IN} = 1.5V to 0.5V, V_{X} or V_{Y} = 2.		+25°C		20		ns
Turn-Off Time	t _{OFF}	$R_L = 50\Omega$, $C_L = 35pF$, Test Circu	uit 2	+25°C		20		115
Address Transition Time	t _{TRANS}	V_{IN} = 4.2V to 0V, V_X or V_Y = 2.1V R_L = 50 Ω , C_L = 35pF, Test Circu		+25°C		30		ns
Break-Before-Make Time Delay	t _D	V_{IN} = 4.2V to 0V, V_X or V_Y = 2.1V R_L = 50 Ω , C_L = 35pF, Test Circu	V, uit 4	+25°C		20		ns
Charge Injection	Q	C _L = 1nF, Test Circuit 5		+25°C		-18		рC
Off Isolation	0	Signal = 0dBm, V_{BIAS} = 2.1V, R_L = 50 Ω , C_L = 35pF,	100kHz	+25°C		-75		dB
On isolation	O _{ISO}	Test Circuit 6	1MHz	+25°C		-55		ив
Channel to Channel Crosstelly	V	Signal = 0dBm, V_{BIAS} = 2.1V, R_L = 50 Ω , C_L = 35pF,	100kHz	+25°C		-106		dB
Channel-to-Channel Crosstalk	X _{TALK}	Test Circuit 6	1MHz	+25°C		-108		ив
-3dB Bandwidth	BW	Signal = 0dBm, V_{BIAS} = 2.1V, R_L = 50 Ω , Test Circuit 6		+25°C		30		MHz
Channel ON Capacitance	$C_{X_(ON)}, C_{Y_(ON)}, C_{X(ON)}, C_{Y(ON)}$			+25°C		146		pF
POWER REQUIREMENTS	, , , , , , , , , , , , , , , , , , , ,				•	•	•	
Power Supply Range	V ₊			Full	1.8		4.2	V
Power Supply Current	I ₊	V ₊ = 4.2V, V _A , V _B , V _{ENABLE} = 4.2\	or 0V	Full			1	μΑ

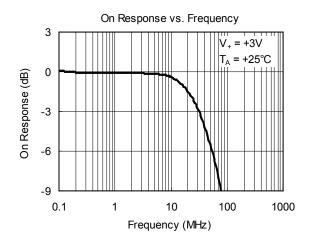
ELECTRICAL CHARACTERISTICS (continued)

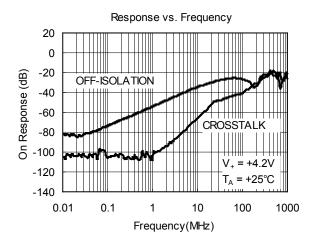
 $(V_+ = +2.7V \text{ to } +3.6V, \text{ GND} = 0V, V_{IH} = +1.6V, V_{IL} = +0.4V, \text{ Full} = -40^{\circ}\text{C}$ to +85°C. Typical values are at $V_+ = +3.0V, T_A = +25^{\circ}\text{C}$, unless otherwise noted.)

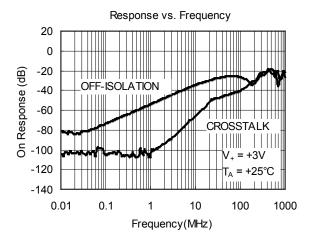
PARAMETER	SYMBOL	CONDITIONS		TEMP	MIN	TYP	MAX	UNITS
ANALOG SWITCH						•	•	
Analog Signal Range	$V_{X}, V_{Y}, V_{X_+}, V_{Y}$			Full	0		V+	V
On Basistana		$V_{+} = 2.7V, I_{X}, I_{Y} = -100mA, V_{X}$	V ₊ = 2.7V, I _X , I _Y = -100mA, V _X , V _Y = 1V,			0.6	0.95	
On-Resistance	R _{on}	Test Circuit 1		Full			1.05	Ω
On-Resistance Match Between	A.D.	V ₊ = 2.7V, I _{X_} , I _{Y_} = -100mA, V _X	, V _Y = 1V,	+25°C		0.05	0.2	0
Channels	ΔR_{ON}	Test Circuit 1		Full			0.24	1 12
On Desistance Flatness	Б	$V_{+} = 2.7V, I_{X}, I_{Y} = -100mA,$		+25°C		0.1	0.2	Ω
On-Resistance Flatness	R _{FLAT(ON)}	V_X , $V_Y = 1V$, 2.5 \overline{V} , Test Circuit 1		Full			0.24	1 12
Source OFF Leakage Current	I _{X_(OFF)} , I _{Y_(OFF)}	V ₊ = 3.6V, V _X , V _Y = 3.3V, 0.3V V _X , V _Y = 0.3V, 3.3V	V,	Full			1	μA
Channel ON Leakage Current	$I_{X_(ON)},\ I_{Y_(ON)},\\ I_{X(ON)}\ ,\ I_{Y(ON)}$	$V_{+} = 3.6V$, V_{X} , $V_{Y} = 0.3V$, $3.3V$, $V_{X_{-}}$, $V_{Y_{-}} = 0.3V$, $3.3V$ or floating		Full			1	μA
DIGITAL INPUTS								
Input High Voltage	V _{INH}			Full	1.5			V
Input Low Voltage	V _{INL}			Full			0.4	V
Input Leakage Current	I _{IN} _	V_A , $V_B = V_{ENABLE} = 0V$ or 2.7V		Full			1	μA
DYNAMIC CHARACTERISTICS								
Turn-On Time	t _{on}	$V_{IN} = 1.5V \text{ to } 0.5V, V_X \text{ or } V_Y = 1.5V \text{ to } 0.5V \text{ or } V_Y = 1.5V o$.5V,	+25°C		33		
Turn-Off Time	t _{OFF}	$R_L = 50\Omega$, $C_L = 35pF$, Test Circ	uit 2	+25°C		20		ns
Address Transition Time	t _{TRANS}	V_{IN} = 1.5V to 0V, V_X or V_Y = 1.5 R_L = 50 Ω , C_L = 35pF, Test Circu		+25°C		36		ns
Break-Before-Make Time Delay	t _D	V_{IN} = 1.5V to 0V, V_X or V_Y = 1.5 R_L = 50 Ω , C_L = 35pF, Test Circ	iV, uit 4	+25°C		18		ns
Charge Injection	Q	C _L = 1nF, Test Circuit 5		+25°C		-18		рС
Off Isolation	0	Signal = 0dBm, V_{BIAS} = 1.5V, R_L = 50 Ω , C_L = 35pF,	100kHz	+25°C		-75		dB
On isolation	O _{ISO}	Test Circuit 6	1MHz	+25°C		-55		uБ
Channel-to-Channel Crosstalk	>	Signal = 0dBm, V_{BIAS} = 1.5V, R_1 = 50 Ω , C_1 = 35pF,	100kHz	+25°C		-106		dB
Chamberto-Chamber Crosstalk	X_{TALK}	Test Circuit 6	1MHz	+25°C		-108		uБ
-3dB Bandwidth	BW	Signal = 0dBm, V _{BIAS} = 1.5V, R _L = 50Ω, Test Circuit 6		+25°C		30		MHz
Channel ON Capacitance	$\begin{array}{c} C_{X_(ON)},C_{Y_(ON)},\\ C_{X(ON)},C_{Y(ON)} \end{array}$			+25°C		146		pF

TYPICAL PERFORMANCE CHARACTERISTICS

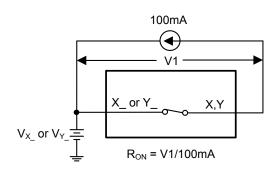




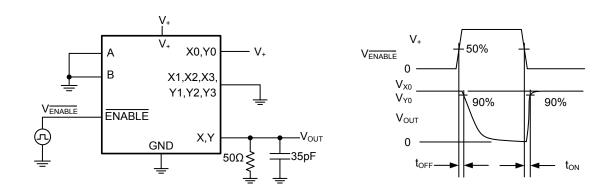




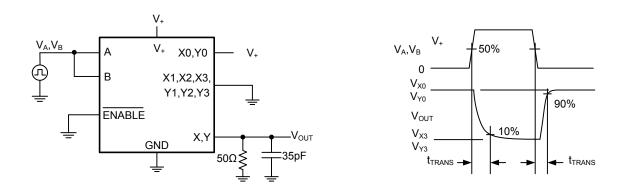
TEST CIRCUITS



Test Circuit 1. On Resistance

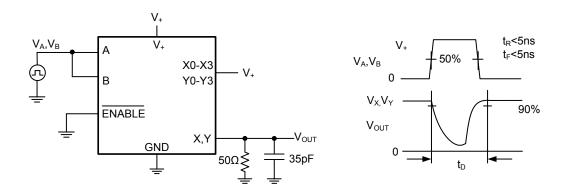


Test Circuit 2. Enable Switching Times ($t_{\text{OFF}},\,t_{\text{ON}}$)

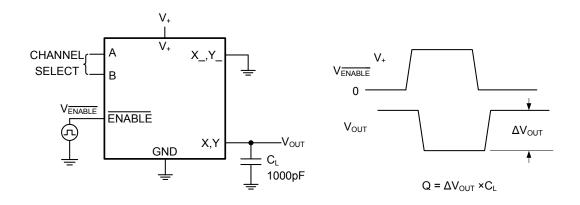


Test Circuit 3. Address Transition Times (trrans)

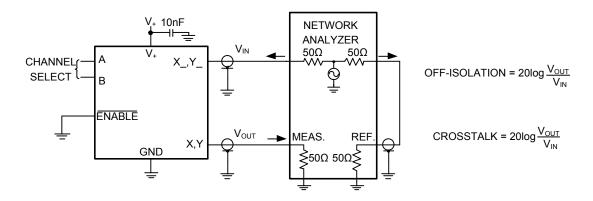
TEST CIRCUITS (continued)



Test Circuit 4. Break-Before-Make Interval (t_D)

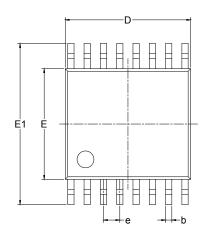


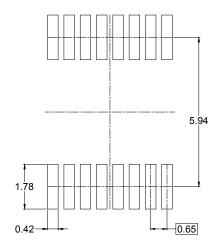
Test Circuit 5. Charge Injection (Q)



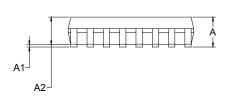
Test Circuit 6. -3dB Bandwidth, Off-Isolation and Crosstalk

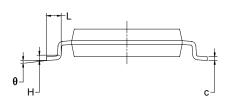
PACKAGE OUTLINE DIMENSIONS TSSOP-16





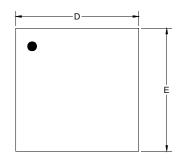
RECOMMENDED LAND PATTERN (Unit: mm)



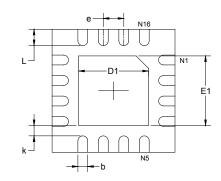


Symbol	_	nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
Α		1.100		0.043	
A1	0.050	0.150	0.002	0.006	
A2	0.800	1.000	0.031	0.039	
b	0.190	0.300	0.007	0.012	
С	0.090	0.200	0.004	800.0	
D	4.900	5.100	0.193	0.201	
Е	4.300	4.500	0.169	0.177	
E1	6.250	6.550	0.246	0.258	
е	0.650	0.650 BSC		BSC	
L	0.500	0.700	0.02	0.028	
Н	0.25	0.25 TYP		TYP	
θ	1°	7°	1°	7°	

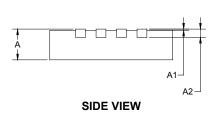
PACKAGE OUTLINE DIMENSIONS TQFN-3×3-16L

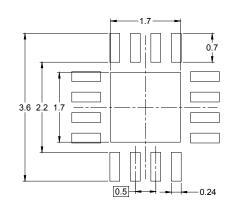


TOP VIEW



BOTTOM VIEW



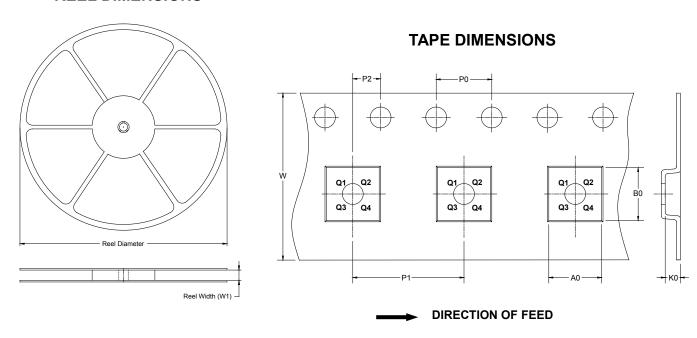


RECOMMENDED LAND PATTERN (Unit: mm)

Symbol		nsions meters	Dimensions In Inches		
,	MIN	MAX	MIN	MAX	
Α	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A2	0.203 REF		0.008 REF		
D	2.900	3.100	0.114	0.122	
D1	1.600	1.800	0.063	0.071	
E	2.900	3.100	0.114	0.122	
E1	1.600	1.800	0.063	0.071	
k	0.200	0.200 MIN		3 MIN	
b	0.180	0.300	0.007	0.012	
е	0.500	0.500 TYP		TYP	
L	0.300 0.500		0.012	0.020	

TAPE AND REEL INFORMATION

REEL DIMENSIONS

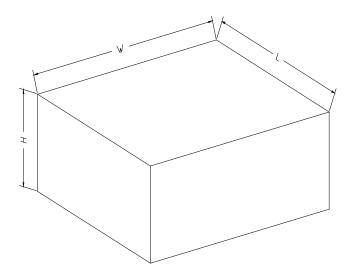


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TSSOP-16	13"	12.4	6.90	5.60	1.20	4.0	8.0	2.0	12.0	Q1
TQFN-3×3-16L	13"	12.4	3.35	3.35	1.13	4.0	8.0	2.0	12.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13″	386	280	370	5